



# PJQ1820

## 20V N-Channel Enhancement Mode MOSFET

Voltage    20 V    Current    800mA

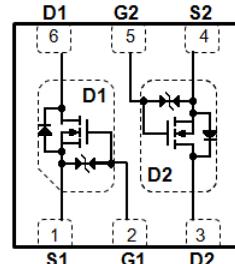
### Features

- Advanced Trench Process Technology
- ESD Protected
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case : DFN1010-6L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.000045 ounces, 0.0013 grams

DFN1010-6L



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	$V_{DS}$	20	V
Gate-Source Voltage	$V_{GS}$	$\pm 8$	
Continuous Drain Current (Note 4)	$I_D$	800	mA
Pulsed Drain Current (Note 1)	$I_{DM}$	1600	
Power Dissipation	$T_a=25^\circ\text{C}$	400	mW
		3.2	$\text{mW}/^\circ\text{C}$
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~150	$^\circ\text{C}$
Typical Thermal resistance - Junction to Ambient (Note 3,4)	$R_{\theta JA}$	312	$^\circ\text{C}/\text{W}$

- Limited only By Maximum Junction Temperature



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## Electrical Characteristics ( $T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.3	0.5	1	
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=500mA$	-	220	300	$m\Omega$
		$V_{GS}=2.5V, I_D=400mA$	-	250	400	
		$V_{GS}=1.8V, I_D=200mA$	-	300	550	
		$V_{GS}=1.5V, I_D=100mA$	-	340	800	
		$V_{GS}=1.2V, I_D=100mA$	-	480	1500	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=20V, V_{GS}=0V$	-	-	1	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 8V, V_{DS}=0V$	-	-	$\pm 10$	
<b>Dynamic</b> (Note 5)						
Total Gate Charge	$Q_g$	$V_{DS}=10V, I_D=500mA,$ $V_{GS}=4.5V$ (Note 2)	-	1.1	-	$nC$
Gate-Source Charge	$Q_{gs}$		-	0.16	-	
Gate-Drain Charge	$Q_{gd}$		-	0.12	-	
Input Capacitance	$C_{iss}$	$V_{DS}=10V, V_{GS}=0V,$ $f=1MHz$	-	46	-	$pF$
Output Capacitance	$C_{oss}$		-	15	-	
Reverse Transfer Capacitance	$C_{rss}$		-	3	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=10V, I_D=500mA,$ $V_{GS}=4.5V,$ $R_G=6\Omega$ (Note 2)	-	5.3	-	$ns$
Turn-On Rise Time	$t_r$		-	22	-	
Turn-Off Delay Time	$t_{d(off)}$		-	43	-	
Turn-Off Fall Time	$t_f$		-	31	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_s$	---	-	-	200	$mA$
Diode Forward Voltage	$V_{SD}$	$I_s=200mA, V_{GS}=0V$	-	0.67	1	V

### NOTES :

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$ .
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{QJA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.



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## TYPICAL CHARACTERISTIC CURVES

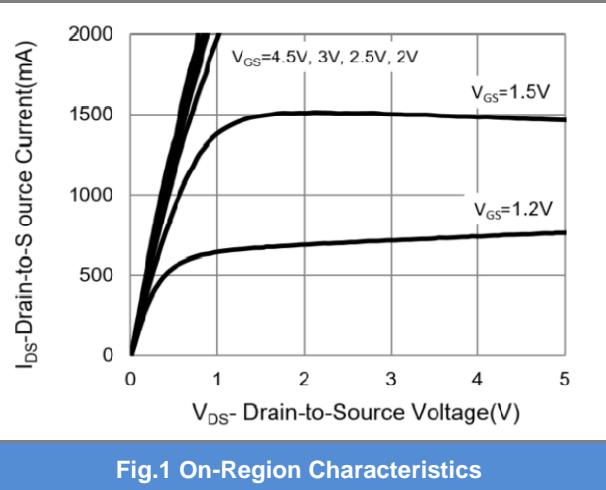


Fig.1 On-Region Characteristics

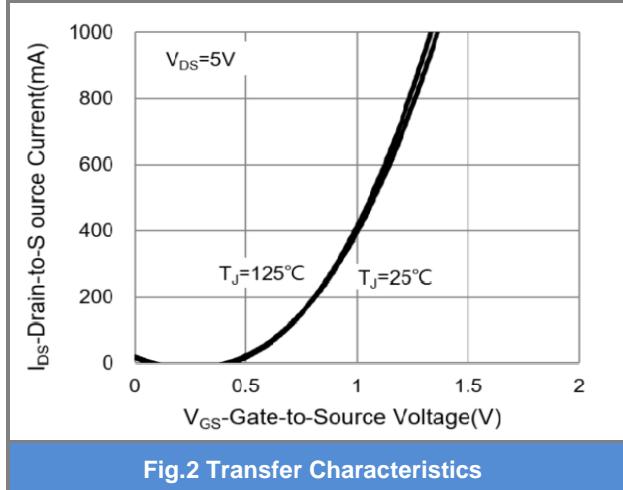


Fig.2 Transfer Characteristics

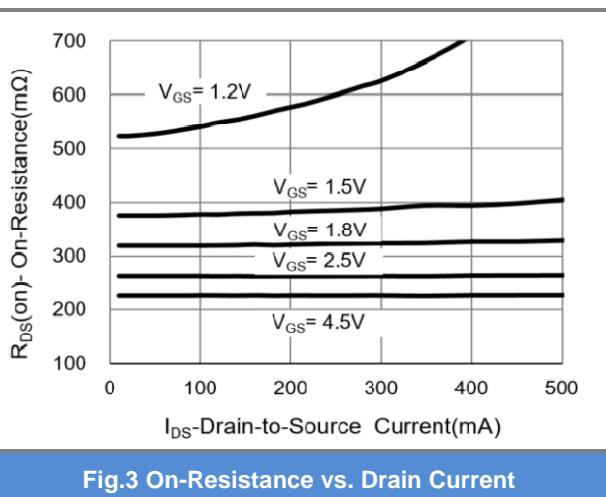


Fig.3 On-Resistance vs. Drain Current

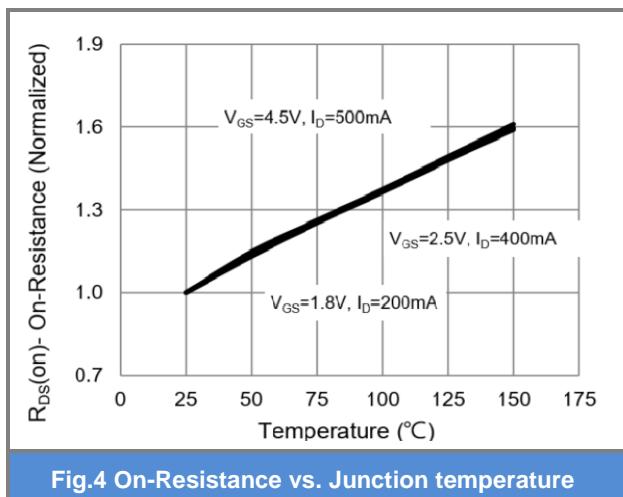


Fig.4 On-Resistance vs. Junction temperature

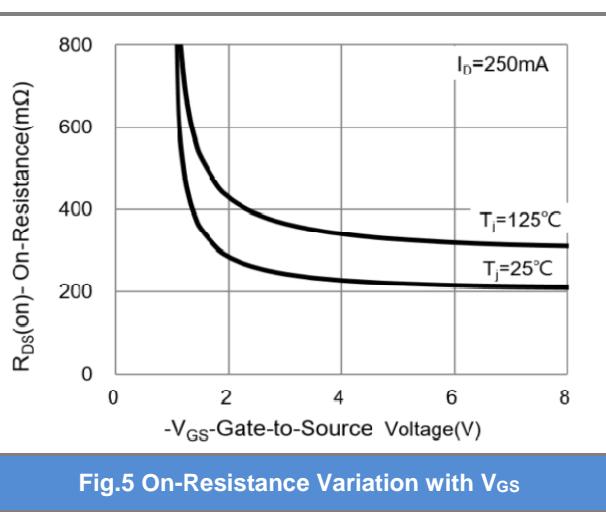


Fig.5 On-Resistance Variation with VGS

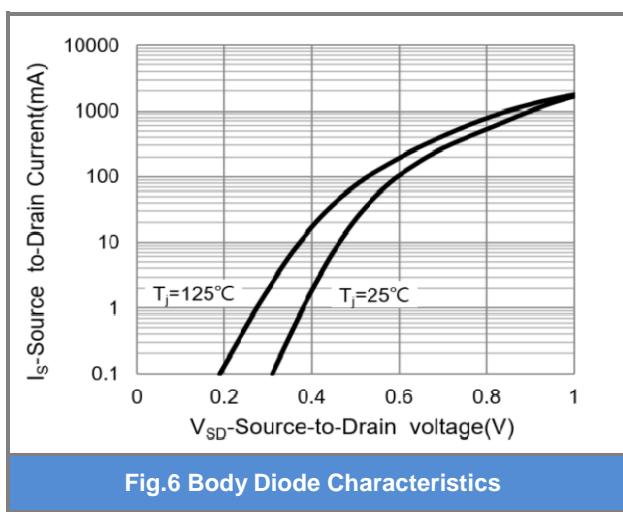


Fig.6 Body Diode Characteristics



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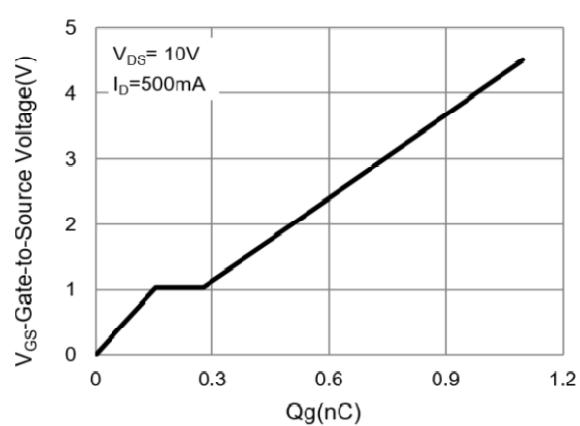


Fig.7 Gate-Charge Characteristics

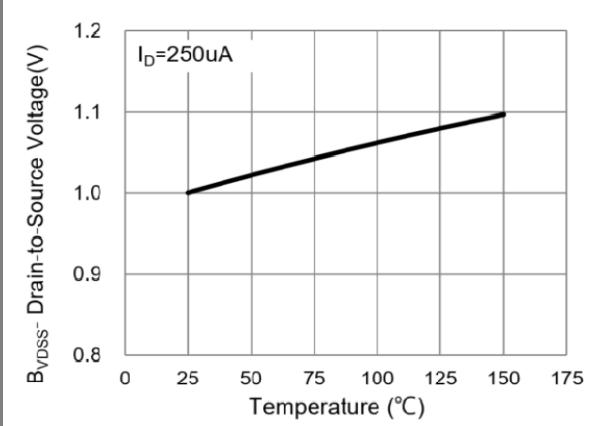


Fig.8 Breakdown Voltage Variation vs. Temperature

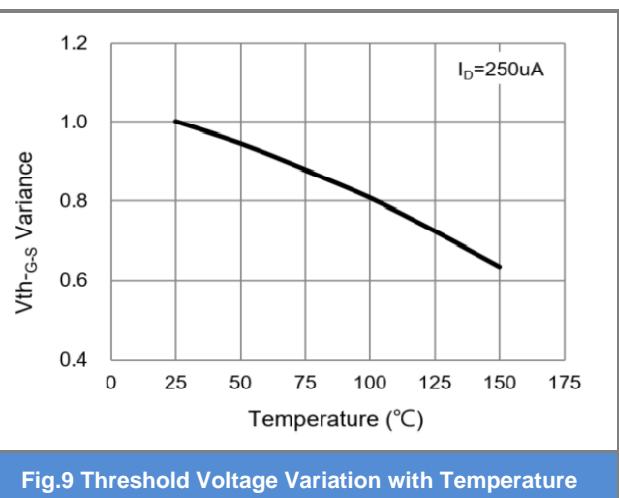


Fig.9 Threshold Voltage Variation with Temperature

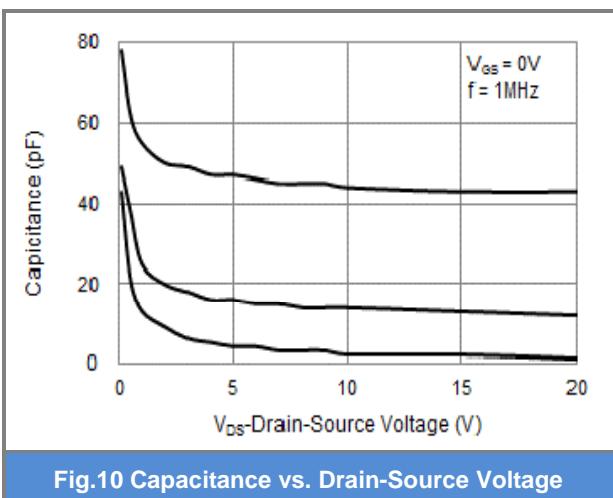


Fig.10 Capacitance vs. Drain-Source Voltage

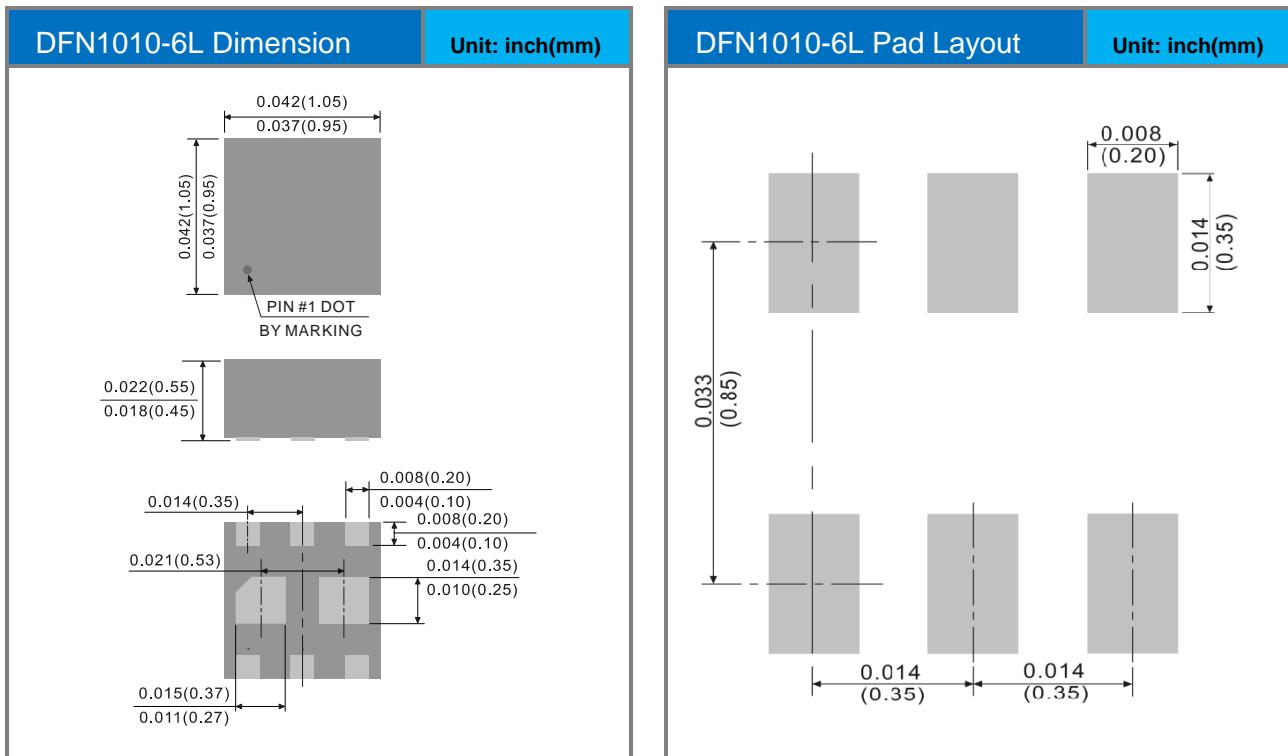


# PJQ1820

## Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ1820_R1_00001	DFN1010-6L	5K pcs / 7" reel	820	Halogen free

## Packaging Information & Mounting Pad Layout





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